



# Linear Voltage Regulator – SiS5219A

Positive Adjustable 1A Low-Dropout Voltage Regulator in bare die form

Rev 1.1  
30/03/22

## Description

SiS5219A is optimised to deliver up to 1A peak output current for start-up conditions where high inrush current is demanded. Output voltage is set by x2 external resistors and enabled or shut down by CMOS or TTL signalling. The device exhibits low dropout voltage and ground current, when disabled current consumption drops to near zero. The part is optimised for ultra-low noise performance delivering 500nV/√Hz typical and lower with an optional bypass capacitor. Rugged with high stability, internal limiting + thermal shutdown features for overload immunity, the part suits use in high performance high reliability applications.

## Features:

- Wide  $V_{IN}$  2.4V - 16V
- Output current capability: 1A
- Low dropout voltage:
  - < 330 mV ( $I_{OUT} = 500mA$ )
  - < 550 mV ( $I_{OUT} = 1000mA$ )
- 0.003% Line, 0.2% Load regulation (Typ)
- Low ground current: < 13mA ( $I_{OUT} = 500mA$ )
- Ultra-Low output noise: 300 nV/√Hz with  $C_{BYPASS}$
- CMOS/TTL-Compatible Enable/Shutdown Control
- Near-Zero Shutdown Current
- Current + thermal limiting + rev. polarity protection
- Low temperature coefficient.

## Ordering Information

The following part suffixes apply:

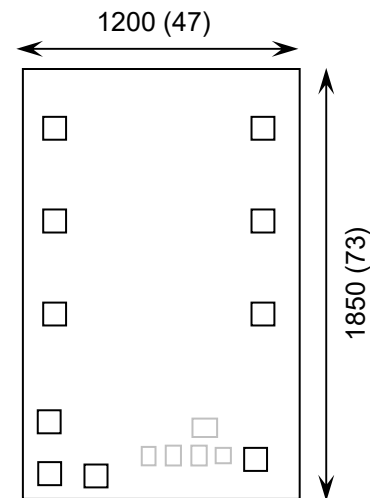
- No suffix - MIL-STD-883 /2010B Visual Inspection
- “H” - MIL-STD-883 /2010B Visual Inspection  
+ MIL-PRF-38534 Class H LAT
- “K” - MIL-STD-883 /2010A Visual Inspection (Space)  
+ MIL-PRF-38534 Class K LAT

LAT = Lot Acceptance Test.

For further information on LAT process flows see below.

[www.siliconsupplies.com/quality/bare-die-lot-qualification](http://www.siliconsupplies.com/quality/bare-die-lot-qualification)

## Die Dimensions in $\mu m$ (mils)



## Supply Formats:

- Default – Die in Waffle Pack (288 per tray capacity)
- Sawn Wafer on Tape – On request
- Unsawn Wafer – On request
- Tape & Reel – On request
- In Metal or Ceramic package – On request

## Mechanical Specification

Die Size (Unsawn)	1200 x 1850 47 x 73	$\mu m$ mils
Minimum Bond Pad Size	100 x 100 3.94 x 3.94	$\mu m$ mils
Die Thickness	280 ( $\pm 20$ ) 11.02 ( $\pm 0.79$ )	$\mu m$ mils
Top Metal Composition	Al	
Back Metal Composition	Ti/Ni/Ag	

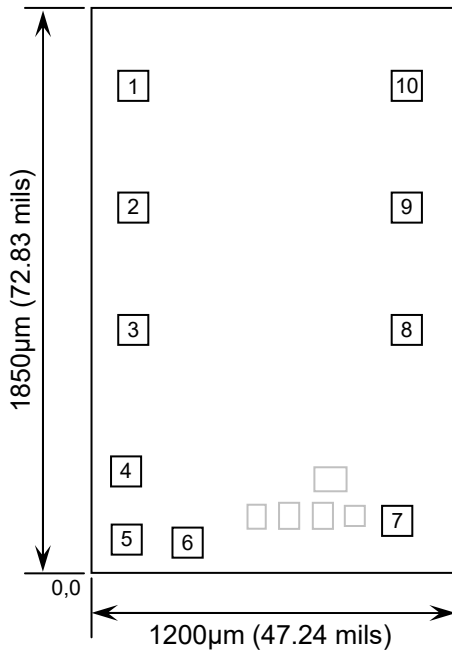




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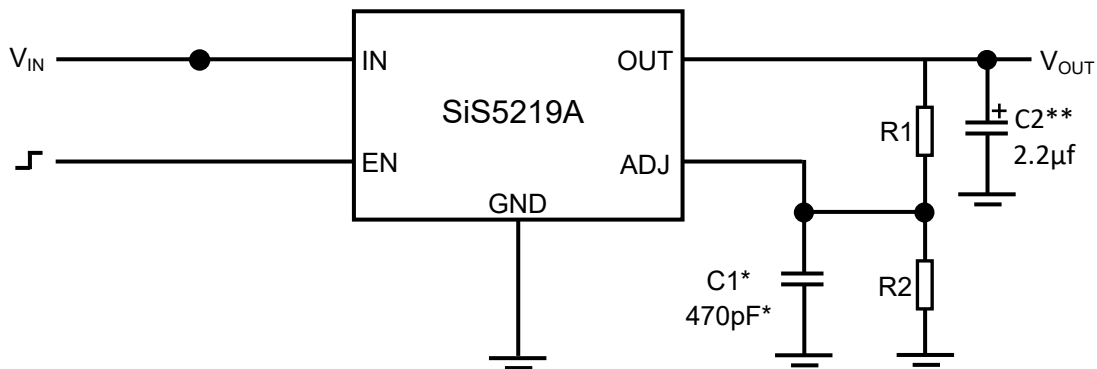
## Pad Layout and Functions



PAD	FUNCTION	COORDINATES (mm)	
		X	Y
1	V <sub>OUT</sub>	0.120	1.514
2	V <sub>OUT</sub>	0.120	1.134
3	V <sub>OUT</sub>	0.120	0.754
4	V <sub>OUT</sub>	0.095	0.315
5	ADJ	0.095	0.100
6	GND	0.290	0.095
7	EN	0.945	0.160
8	V <sub>IN</sub>	0.975	0.754
9	V <sub>IN</sub>	0.975	1.134
10	V <sub>IN</sub>	0.975	1.514

CONNECT CHIP BACK TO GND

## Typical Application



1.24V - 16V Adjustable Regulator

$$V_{OUT} = 1.242V \times \left( \frac{R2}{R1} + 1 \right)$$

\* Include the optional bypass capacitor from ADJ to GND for ultra-low output noise.

\*\* C2 is not required for stability; however it does improve transient response.

For optimum stability and transient response locate C1 C2 as close as possible to the regulator.  
Although ADJ is a high-impedance input, for best performance, R2 should not exceed 470 kΩ





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## Absolute Maximum Ratings<sup>1</sup>

PARAMETER	SYMBOL	VALUE	UNIT
Input–Output Voltage differential	$V_{IN} - V_{OUT}$	20	V
Power Dissipation	$P_D$	Internally Limited	
Operating Junction Temperature	$T_J$	-40 to 125	°C
Storage Temperature	$T_{STG}$	-65 to 150	°C

## Recommended Operating Conditions

PARAMETER	SYMBOL	MIN	MAX	UNIT
Input Voltage	$V_{IN}$	2.4	16	V
Enable Voltage	$V_{EN}$	0	$V_{IN}$	V
Output Current	$I_{OUT}$	0.1	1000	mA
Operating Junction Temperature Range	$T_J$	-40 to 125		°C

## DC Electrical Characteristics

$V_{IN} = V_{OUT} + 1V$ ,  $C_{OUT} = 2.2\mu F$ ,  $I_{OUT} = 10mA$ ,  $V_{EN} = 2.25V$ ,  $-40^\circ C < T_J < +125^\circ C$   
(unless noted otherwise)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNITS
Reference Voltage	$V_{REF}$	$2.4V \leq V_{IN} \leq 16V$ , $100\mu A \leq I_L \leq 1A$ , $T_J = 25^\circ C$	1.228	1.24	1.252	V
		$2.4V \leq V_{IN} \leq 16V$ , $100\mu A \leq I_L \leq 1A$	1.215	-	1.265	
		$1.8V \leq V_{OUT} \leq (V_{IN} - 1V)$ , $100\mu A \leq I_L \leq 1A$	1.203	1.24	1.277	V
Reference Voltage Temperature Coefficient	$\Delta V_{REF}/\Delta T$		-	20	-	ppm/°C
Line Regulation	$\Delta V_{OUT}$	$V_{IN} = V_{OUT} + 1V$ to 16V, $I_{OUT} = 10mA$ , $T_J = 25^\circ C$	-	0.003	0.05	% / $V_{OUT}$
Load Regulation <sup>2</sup>		$V_{IN} = V_{OUT} + 1V$ to 16V, $I_{OUT} = 10mA$	-	-	0.1	
		$I_{OUT} = 100\mu A$ to 1A, $T_J = 25^\circ C$	-	0.2	1.0	% / A
		$I_{OUT} = 100\mu A$ to 1A	-	-	1.4	
Output Voltage Temperature Coefficient	$\Delta V_{OUT}/\Delta T$		-	40	100	ppm/°C
Dropout Voltage <sup>3</sup>	$V_{IN} - V_{OUT}$	$I_{OUT} = 100\mu A$ , $T_J = 25^\circ C$	-	30	60	mV
		$I_{OUT} = 100\mu A$	-	-	80	
		$I_{OUT} = 100mA$ , $T_J = 25^\circ C$	-	100	200	
		$I_{OUT} = 100mA$	-	-	250	
		$I_{OUT} = 500mA$ , $T_J = 25^\circ C$	-	250	330	
		$I_{OUT} = 500mA$	-	-	410	
		$I_{OUT} = 750mA$ , $T_J = 25^\circ C$	-	310	440	
		$I_{OUT} = 750mA$	-	-	500	
		$I_{OUT} = 1A$ , $T_J = 25^\circ C$	-	400	550	
		$I_{OUT} = 1A$	-	-	630	





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(unless noted otherwise)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNITS
Enable Input Voltage	$V_{EN}$	Logic Low (off). $T_J = 25^{\circ}C$	-	-	0.40	V
		Logic Low (off)	-	-	0.18	
		Logic High (on)	2.0	-	-	
Enable Input Current	$I_{EN}$	$V_{EN} = 0.4V$ . $T_J = 25^{\circ}C$	-	-	1	$\mu A$
		$V_{EN} = 0.18V$	-	-	2	
		$V_{EN} = 0.20V$ . $T_J = 25^{\circ}C$	-	12	20	
		$V_{EN} = 0.20V$	-	-	30	
Ground Pin Current <sup>4</sup>	$I_{GND}$	$I_{OUT} = 100\mu A$ , $V_{IN} = V_{OUT} + 1.0V$ , $T_J = 25^{\circ}C$	-	0.08	0.13	mA
		$I_{OUT} = 100\mu A$ , $V_{IN} = V_{OUT} + 1.0V$	-	-	0.17	
		$I_{OUT} = 100mA$ , $V_{IN} = V_{OUT} + 1.0V$ , $T_J = 25^{\circ}C$	-	0.95	2	
		$I_{OUT} = 100mA$ , $V_{IN} = V_{OUT} + 1.0V$	-	-	3	
		$I_{OUT} = 500mA$ , $V_{IN} = V_{OUT} + 1.0V$ , $T_J = 25^{\circ}C$	-	9	13	
		$I_{OUT} = 500mA$ , $V_{IN} = V_{OUT} + 1.0V$	-	-	15	
		$I_{OUT} = 750mA$ , $V_{IN} = V_{OUT} + 1.0V$ , $T_J = 25^{\circ}C$	-	18	25	
		$I_{OUT} = 750mA$ , $V_{IN} = V_{OUT} + 1.0V$	-	-	30	
		$I_{OUT} = 1A$ , $V_{IN} = V_{OUT} + 1.0V$ , $T_J = 25^{\circ}C$	-	31	50	
		$I_{OUT} = 1A$ , $V_{IN} = V_{OUT} + 1.0V$	-	-	60	
	$I_{GND(off)}$	$V_{EN} = 0.4V$ . $T_J = 25^{\circ}C$	-	-	3	$\mu A$
$V_{EN} = 0.18V$		-	-	8		
Adjustment Pin Current	$I_{ADJ}$	$T_J = 25^{\circ}C$	-	40	80	nA
			-	-	120	
Adjustment Pin Current Change	$\Delta I_{ADJ}/\Delta T$		-	0.1	-	nA/ $^{\circ}C$
Ripple Rejection	PSRR	$f = 120Hz$	60	-	-	dB
Current Limit	$I_{LIMIT}$	$V_{OUT} = 0V$ . $T_J = 25^{\circ}C$	-	3000	-	mA
		$V_{OUT} = 0V$	-	-	5000	
Output Noise	$e_{no}$	$I_{OUT} = 50mA$ , $C_{OUT} = 2.2\mu F$ , $C_{bypass} = 0$	-	500	-	nV/ $\sqrt{Hz}$
		$I_{OUT} = 50mA$ , $C_{OUT} = 2.2\mu F$ , $C_{bypass} = 470pF$	-	300	-	

1. Operation above the absolute maximum rating may cause device failure. Operation at the absolute maximum ratings, for extended periods, may reduce device reliability. 2. Regulation is measured at a constant junction temperature, using pulse testing with a low duty cycle. 3. Dropout voltage is defined as the input to output differential at which the output voltage drops 2% below its nominal value measured at 1V differential. 4.  $I_{GND}$  is the quiescent current.  $I_{IN} = I_{GND} + I_{OUT}$ .





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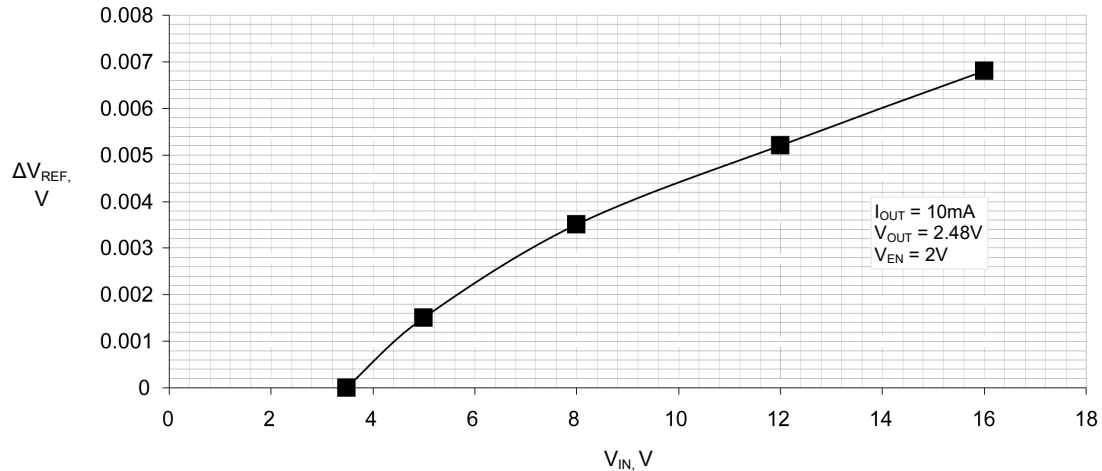


Figure 1 – Reference Voltage stability Versus Input Voltage

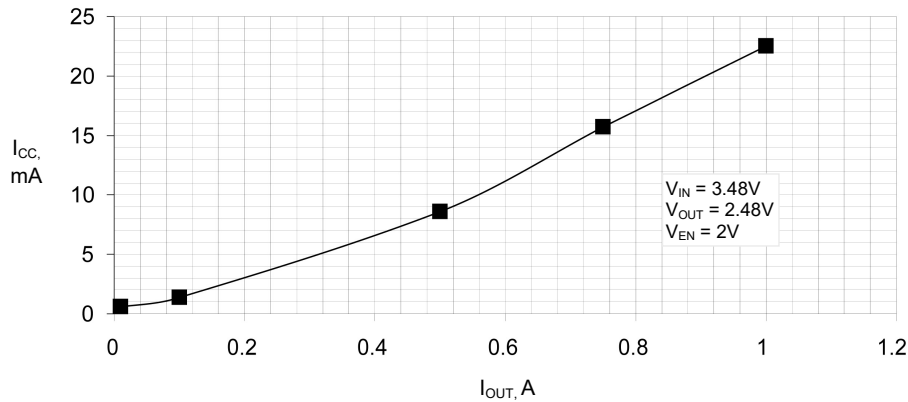


Figure 2 – Supply Current Versus Output Current

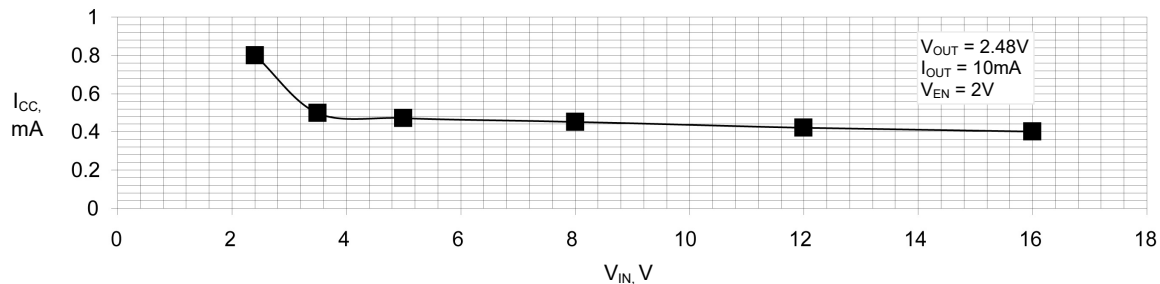


Figure 3 – Supply Current Versus Input Voltage





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Typical Electrical Characteristics,  $T_J = 25^\circ\text{C}$  (unless noted otherwise)

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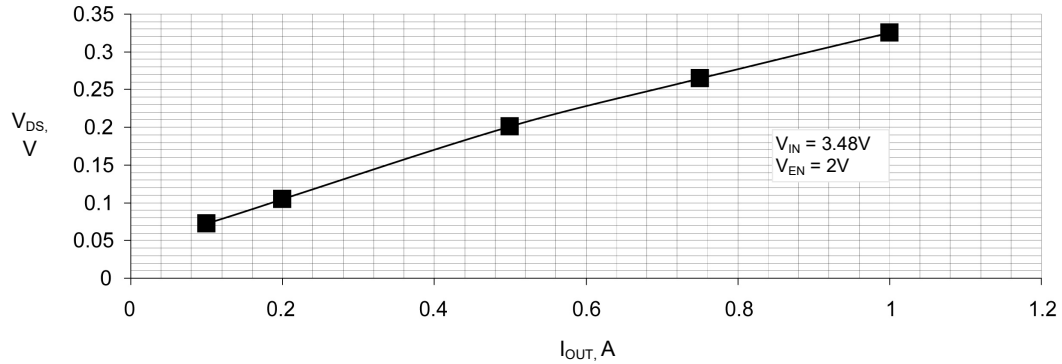


Figure 4 –  $V_{DS}$  Versus Output Current

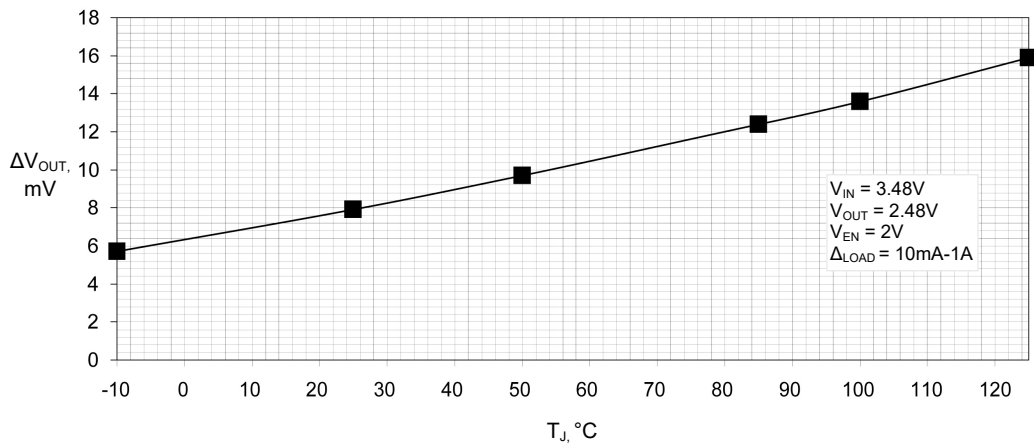


Figure 5 –  $\Delta V_{OUT}$  at  $\Delta I_{LOAD}$  Versus Junction Temperature

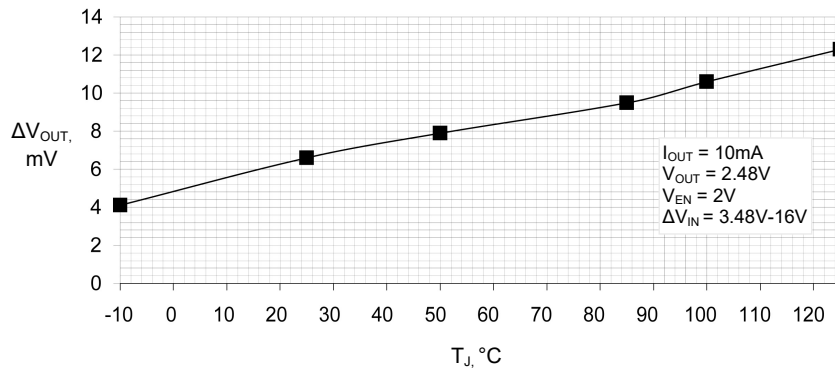


Figure 6 –  $\Delta V_{OUT}$  at  $\Delta V_{IN}$  Versus Junction Temperature





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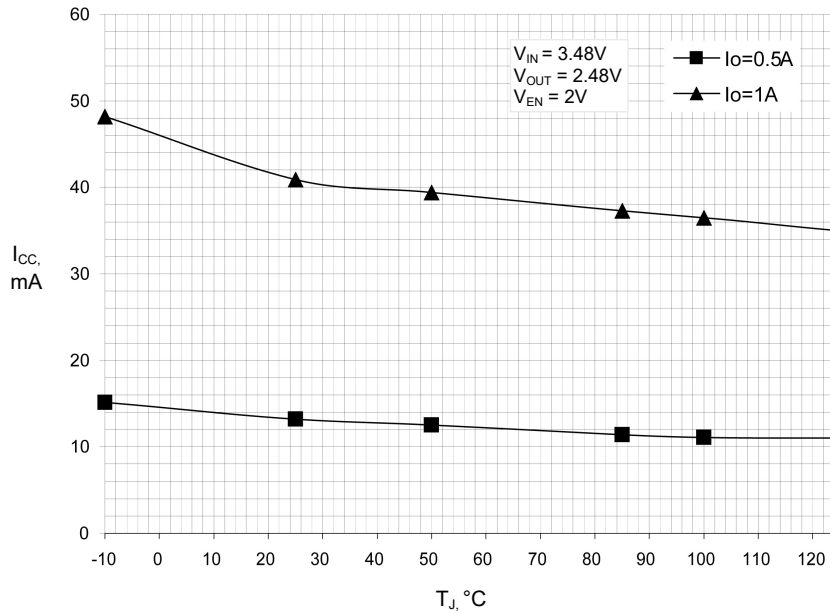


Figure 7 – Supply Current Versus Junction Temperature

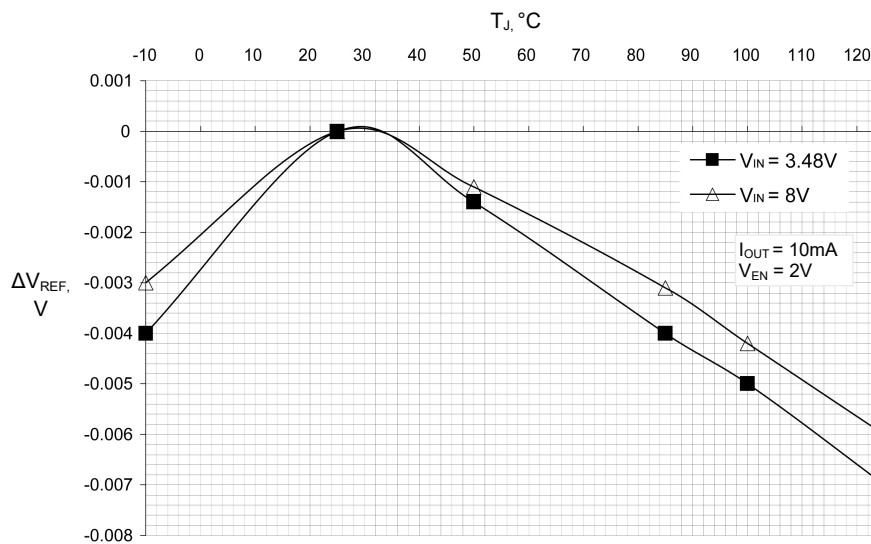


Figure 8 –  $\Delta V_{REF}$  Versus Junction Temperature,  $I_{OUT} = 10mA$





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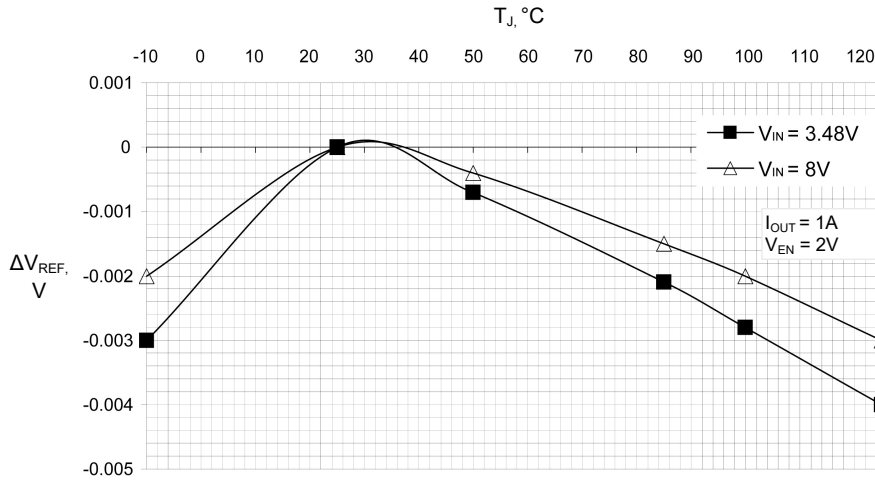


Figure 9 –  $\Delta V_{REF}$  Versus Junction Temperature,  $I_{OUT} = 1A$

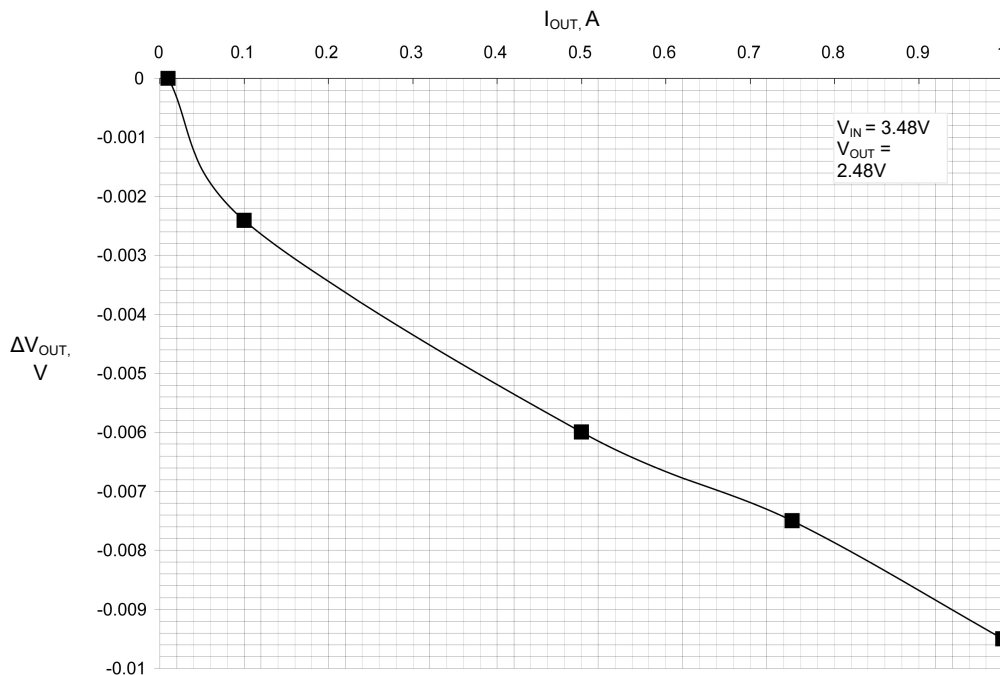


Figure 10 –  $\Delta V_{OUT}$  Versus Output Current

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